Document Title

128K X 8 LOW VOLTAGE OTP CMOS EPROM

Revision History

Rev. No.	History	Issue Date	Remark
0.0	Initial issue	July 14, 1998	

Preliminary — *128K X 8 LOW VOLTAGE OTP CMOS EPROM*

Features

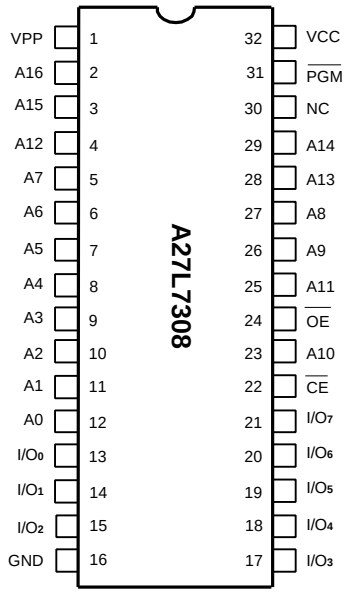
- 131,072 X 8 bit organization
- Programming voltage: 12.75V
- VCC power supply range: 3.0V to 3.6V
- Access time: 120 ns (max.)
- Current: Operating: 15mA (max.)
  Standby: 50µA (max.)
- All inputs and outputs are directly TTL-compatible
- Available in 32-pin DIP and 32-pin PLCC

General Description

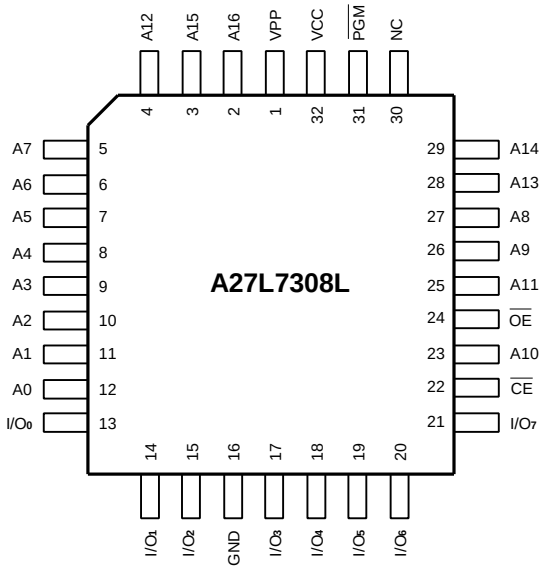
The A27L7308 chip is a low-voltage 1,048,576 bit one-time programmable read only memory (OTP EPROM) organized as 128K by 8 bits. The A27L7308 requires only 3.3V power supply in normal read mode operation and any input signals are TTL levels. The A27L7308 is available in industry standard 32 pin dual-in-line and 32 lead PLCC packages.

Pin Configurations

■ **DIP**



■ **PLCC**



Pin Configurations

Pin Name	Function
A0-A17	Address Inputs
I/O_0-I/O_7	Data Inputs / Outputs
$\overline{CE}$	Chip Enable
$\overline{OE}$	Output Enable
$\overline{PGM}$	Program Strobe
VPP	Program Power Supply
VCC	Power Supply
GND	Ground
NC	No Internal Connection

Operating Modes and Truth Table

Mode	$\overline{CE}$	$\overline{OE}$	$\overline{PGM}$	A0	A1	A9	VPP	VCC	I/O_7-I/O_0
Read	V_{IL}	V_{IL}	X	X	X	X	VCC	VCC	Data Out
Output Disable	V_{IL}	V_{IH}	X	X	X	X	VCC	VCC	Hi-Z
Standby	V_{IH}	X	X	X	X	X	VCC	VCC	Hi-Z
Program	V_{IL}	V_{IH}	V_{IL} Pulse	X	X	X	12.75V	6.25V	Data In
Program Verify	V_{IL}	V_{IL}	V_{IH}	X	X	X	12.75V	6.25V	Data Out
Program Inhibit	V_{IH}	X	X	X	X	X	12.75V	6.25V	Hi-Z
Manufacturer Code[3]	V_{IL}	V_{IL}	V_{IH}	V_{IL}	V_{IL}	V_{ID}	VCC	VCC	37H
Device Code[3]	V_{IL}	V_{IL}	V_{IH}	V_{IH}	V_{IL}	V_{ID}	VCC	VCC	61H
Continuation Code[3]	V_{IL}	V_{IL}	V_{IH}	V_{IL}	V_{IH}	V_{ID}	VCC	VCC	7FH

Notes:
1. X = Either V_{IH} or V_{IL}.
2. V_{ID} = 12V ± 0.5V.
3. A2 ~ A8 = A10 ~ A16 = V_{IL} (For auto identification)

Functional Description

Read Mode

The A27L7308 has two control functions, both of which must be logically active in order to obtain data at the outputs. $\overline{CE}$ is the power control and should be used for device selection. $\overline{OE}$ is the output control and should be used to data to the output pins, which is independent of device selection. Assuming that addresses are stable, address access time (t_{AA}) is equal to the delay from $\overline{CE}$ to output (t_{CE}). Data is available at the output after a delay (t_{OE}) from the falling edge of $\overline{OE}$, as long as $\overline{CE}$ has been low and the addresses have been stable for at least $t_{AA} - t_{OE}$.

Standby Mode

The A27L7308 has a standby mode which reduces the active current from 15mA to 50µA. The A27L7308 is placed in the standby mode by applying a CMOS high signal to $\overline{CE}$. When in the standby mode, the output are in a high impedance state, independent of the $\overline{OE}$.

Auto Identify Mode

The auto identify mode allows the reading out of a binary code from a EPROM that will identify its manufacturer and type. This mode is intended for use by programming equipment for the purpose of automatically matching the device to be programmed with its corresponding programming algorithm.

To activate the mode, the programming equipment must apply 12.0V ± 0.5V on address line A9 of the A27L7308. Three identification code can be read from data output pin by toggling A0 and A1. The other addresses must be held at V_{IL} during this mode. Byte 0 (with A0 at V_{IL}, A1 at V_{IL}) represents the manufacturer code which is 37H. Byte 1 and Byte 2 represent the device code and continuation code, which is 61H and 7FH respectively. All identifiers for these codes will possess odd parity, with MSB (IO_7) defined the parity bit.

Absolute Maximum Ratings*

Ambient Operating Temperature (T_A) . . . . -10°C to +85°C
Storage Temperature Plastic Package (T_{STG}) . . . . . -55°C to 125°C
Applied Input Voltage (V_I):
All Pins Except A9, VPP and VCC . . . . . -0.6V to VCC + 0.6V
A9, VPP . . . . . -0.6V to 13.5V
VCC . . . . . -0.6V to 7.0V
Output Voltage (V_O) . . . . . -0.6V to 7.0V (Note 1)

*Comments

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to this device. These are stress ratings only. Functional operation of this device at these or any other conditions above those indicated in the operational sections of this specification is not implied or intended. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.

Notes:
1. During voltage transitions, the input may undershoot GND to -2.0V for periods less than 20 ns. Maximum DC voltage on input and I/O may overshoot to VCC + 2.0V for periods less than 20 ns.
2. When transitions, A9 and VPP may undershoot GND to -2.0V for periods less than 20 ns. Maximum DC input voltage on A9 and VPP is +13.5V which may overshoot to 14.0V for period less than 20 ns.

Read Mode DC Electrical Characteristics (Ta = 0°C to 70°C, VCC =3.3V ± 10%, VPP = VCC)

Symbol	Parameter	Min.	Max.	Unit	Conditions
V_{OH}	Output High Voltage	2.4		V	I_{OH} = -100μA
V_{OL}	Output Low Voltage		0.45	V	I_{OL} = 1.6mA
V_{IH}	Input High Voltage	2.0	VCC + 0.5	V	
V_{IL}	Input Low Voltage	-0.5	0.6	V	
I_{LI}	Input Leakage Current	-1	+1	μA	VCC = max. Vin = 0V to VCC
I_{LO}	Output Leakage Current	-1	+1	μA	VCC = max. Vout = 0V to VCC
I_{CC}	VCC Read Operating Current		15	mA	VCC = max. $\overline{CE}$ = V_{IL}, $\overline{OE}$ = V_{IL} Iout = 0mA
I_{SB}	VCC Standby Current (TTL)		1	mA	VCC = max. $\overline{CE}$ = V_{IH}
I_{SB1}	VCC Standby Current (CMOS)		50	μA	VCC = max. $\overline{CE}$ = VCC - 0.2V
I_{PP}	VPP Current During Read		10	μA	$\overline{CE}$ = $\overline{OE}$ = V_{IL}, VPP = VCC
I_{ID}	A9 Auto Select Current		100	μA	A9 = V_{ID}, VCC = max.

Capacitance (T_A = 25°C, f = 1.0MHz)

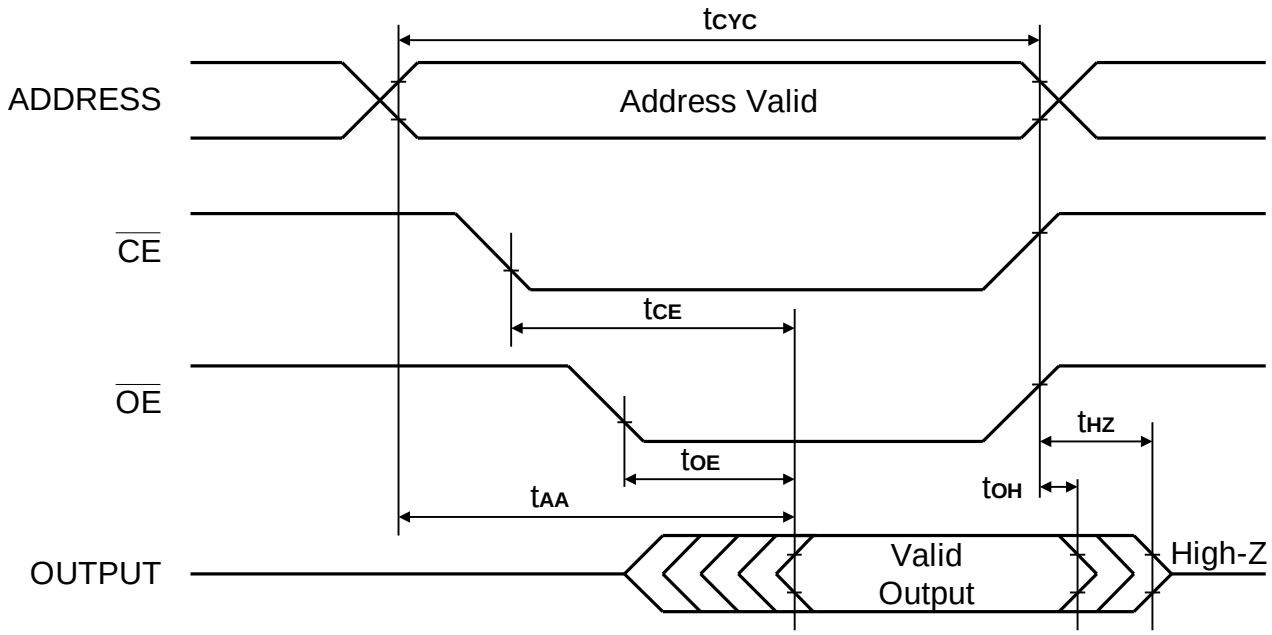
Symbol	Parameter	Min.	Max.	Unit	Conditions
C_{IN}	Input Capacitance		8	pF	V_{IN} = 0V
C_{out}	Output Capacitance		8	pF	V_{out} = 0V

* These parameters are sampled and not 100% tested.

Read Mode AC Characteristics (Ta = 0°C to 70°C, VCC = 3.3V ± 10%, VPP = VCC)

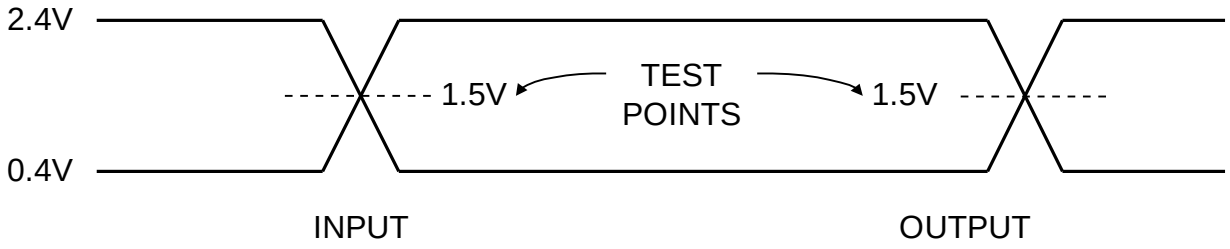
Symbol	Parameter	120ns		Unit
		Min.	Max.	
t_{CYC}	Cycle Time	120		ns
t_{AA}	Address Access Time		120	ns
t_{CE}	Chip Enable Access Time		120	ns
t_{OE}	Output Enable Access Time		50	ns
t_{OH}	Output Hold after Address, $\overline{CE}$ or $\overline{OE}$, whichever Occurred First	0		ns
t_{HZ}	Output High Z Delay		30	ns

Read Mode Switching Waveforms

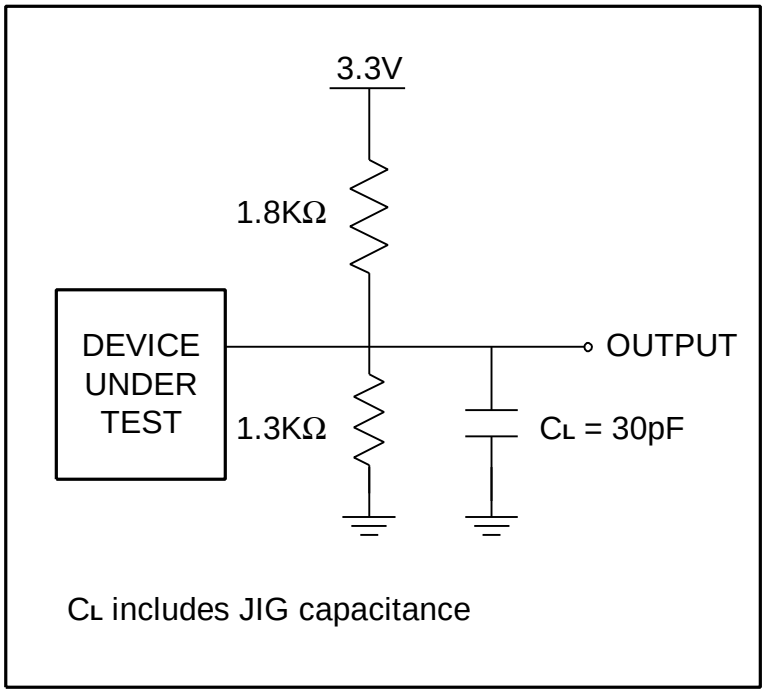


AC Measurement Conditions

for 120 ns ① Input Rise and Fall Times ≤ 5 ns
Input Pulse Voltage: 0.4V to 2.4Volt
Input and Output Timing Ref. Voltage: 1.5Volt



AC Testing Load Circuit



Programming and Program Verify

The programming flowchart is shown in Page 10.

The A27L7308 is shipped with all bits being set to "1". Programming causes relevant bits to be changed to "0". The programming mode is started by setting VCC to +6.25V and VPP to +12.75V, while $\overline{CE}$ and $\overline{PGM}$ are at V_{IL}, and $\overline{OE}$ is at V_{IH}. Data to be programmed can be directly input in the 8 bit format through the data bus.

The write programming algorithm reduces programming time by using 100µs pulse followed by a byte verification to determine whether the byte has been successfully programmed. If the data does not pass the verification, an additional pulse programming is applied for a maximum of 25 pulses. On completion of 1 byte programming and, the verified address is incremented. After the final address is completed, all bytes are verified again with VCC = 5.0 Volt.

Program Inhibit

This mode is used to program one of multiple A27L7308 whose $\overline{OE}$, $\overline{PGM}$, VPP, VCC, address bus and data bus are connected in parallel. When programming is performed, other A27L7308 can be inhibited from being programmed by setting their $\overline{CE}$ pins to V_{IH}.

Programming Mode DC Characteristics (Ta = 0°C to 70°C, VCC = 6.25V ± 0.25V, VPP = 12.75V ± 0.25V)

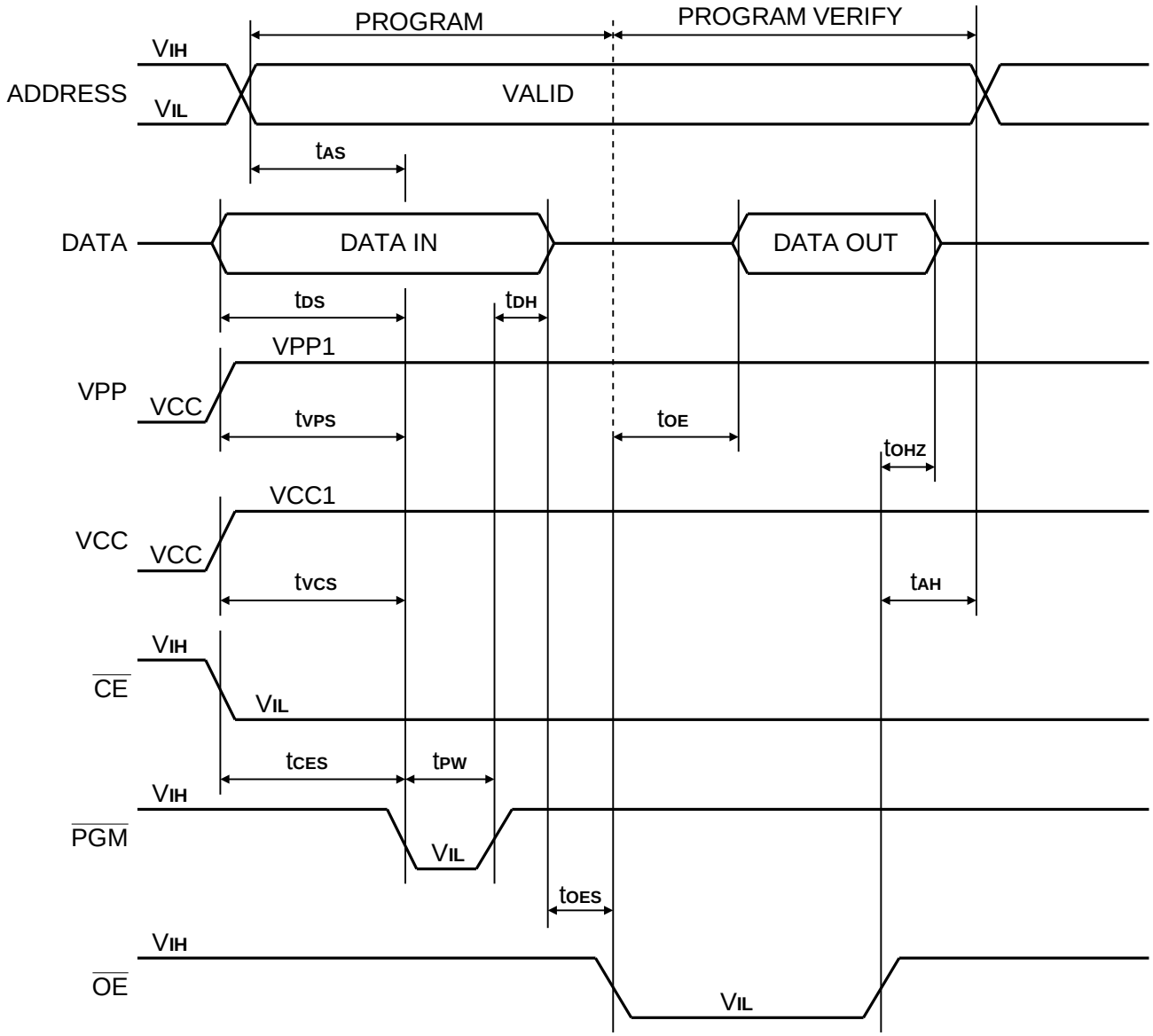
Symbol	Parameter	Min.	Max.	Unit	Test Conditions
V_{IH}	Input High Voltage	2.0	VCC + 0.5	V	
V_{IL}	Input Low Voltage	-0.5	0.6	V	
I_{LI}	Input Leakage Current	-1	+1	µA	VCC = max. Vin = 0V to VCC
I_{CC}	VCC Current During Program		50	mA	
I_{PP}	VPP Current During Program		50	mA	$\overline{CE}$ = V_{IL}
V_{ID}	A9 Auto Select Voltage	11.5	12.5	V	A9 = V_{ID}
VCC1	Programming Supply Voltage	6.0	6.5	V	
VPP1	Programming Voltage	12.5	13	V	

Note: VCC must be applied simultaneously or before VPP and removed simultaneously or after VPP.

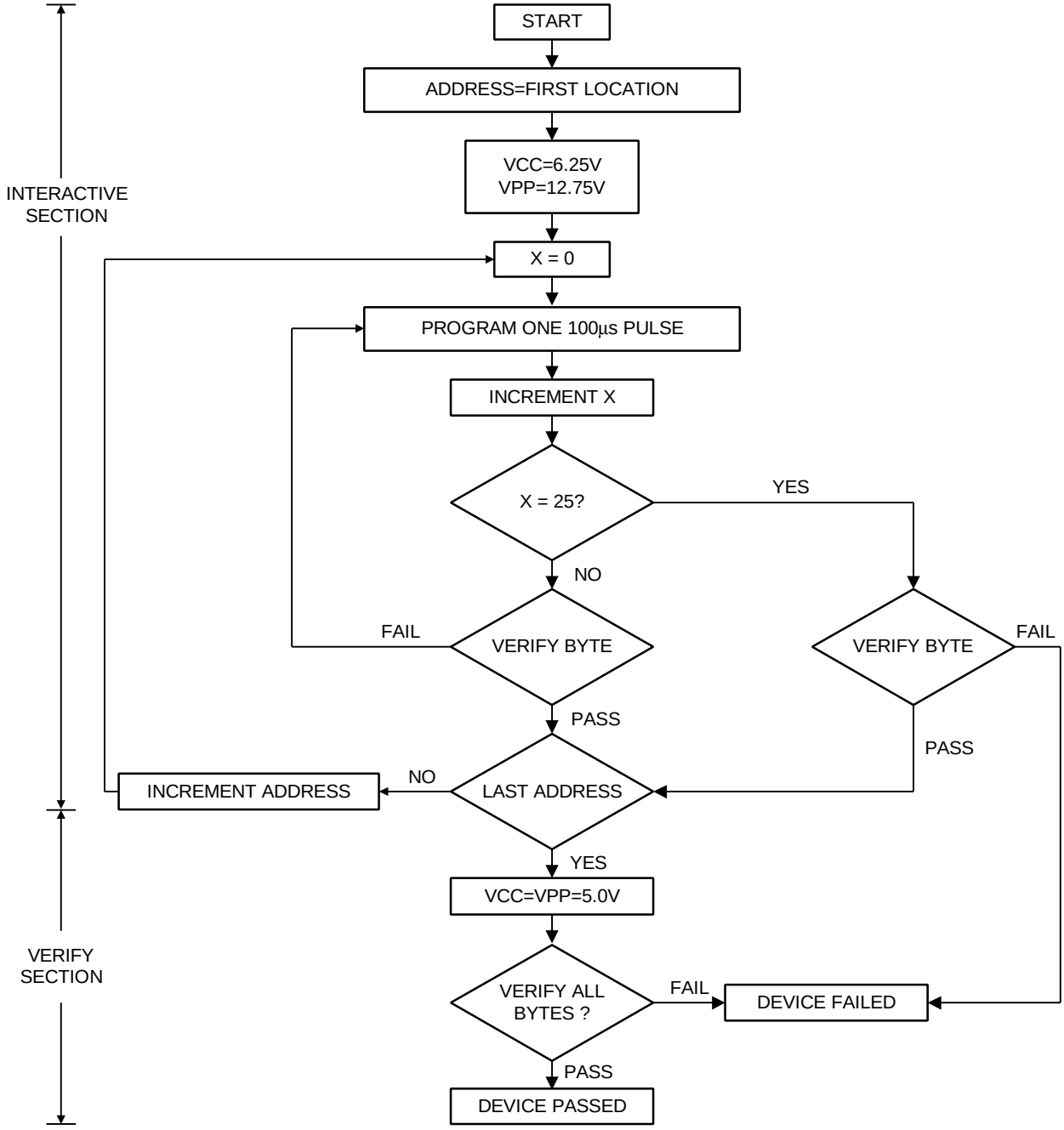
Programming Mode AC Characteristics (Ta = 0°C to 70°C, VCC= 6.25V ± 0.25V, VPP = 12.75V ± 0.25V)

Symbol	Parameter	Min.	Max.	Unit
t_{AS}	Address Valid to Program Low	2		µs
t_{DS}	Input Valid to Program Low	2		µs
t_{VPS}	VPP High to Program Low	2		µs
t_{VCS}	VCC High to Program Low	2		µs
t_{CES}	$\overline{CE}$ Low to Program Low	2		µs
t_{PW}	Program Pulse Width	95	105	µs
t_{DH}	Program High to Input transition	2		µs
t_{OES}	Input Transition to $\overline{OE}$ Low	2		µs
t_{OE}	$\overline{OE}$ Low to Output Valid		100	ns
t_{OHZ}	$\overline{OE}$ High to Output Hi-Z		130	ns
t_{AH}	$\overline{OE}$ High to Address Transition	0		ns

Programming and Verify Mode AC Waveforms



Programming Flowchart



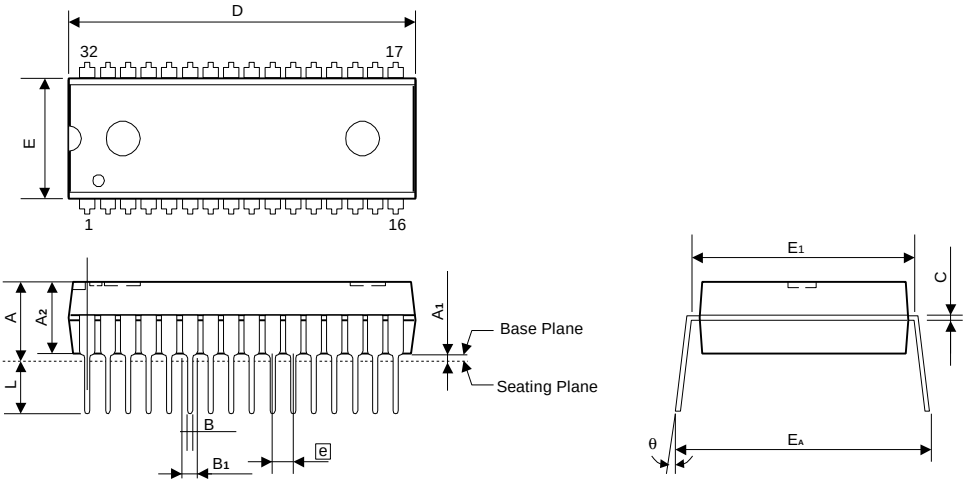
Ordering Information

Part No.	Access Time (ns)	Operating Current Max. (mA)	Standby Current Max. (μA)	Package
A27L7308-12	120	15	50	32Pin DIP
A27L7308L-12	120	15	50	32Pin PLCC

Package Information

P-DIP 32L Outline Dimensions

unit: inches/mm



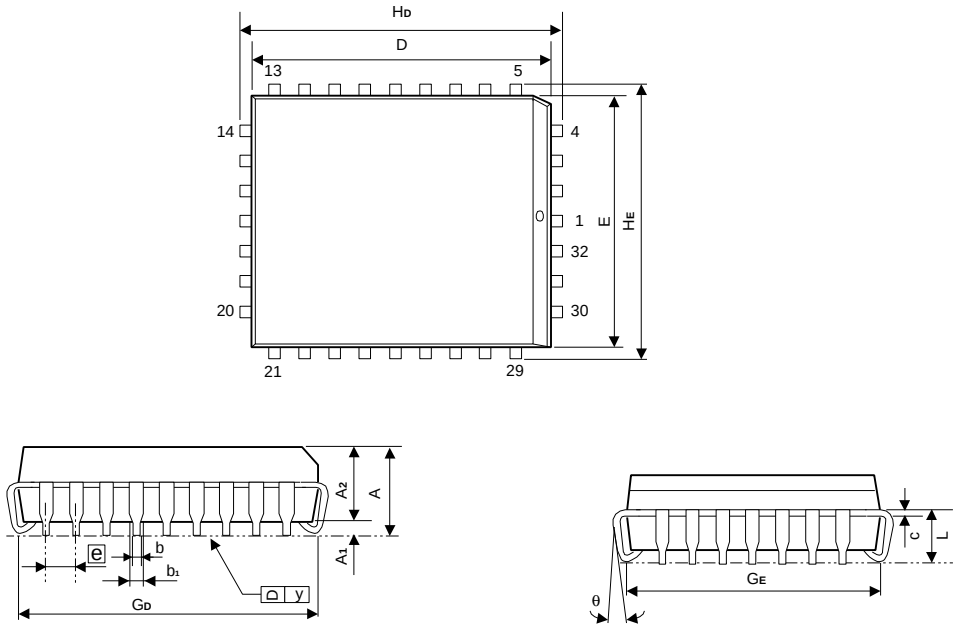
Symbol	Dimensions in inches			Dimensions in mm		
	Min	Nom	Max	Min	Nom	Max
A	-	-	0.210	-	-	5.334
A_1	0.015	-	-	0.381	-	-
A_2	0.149	0.154	0.159	3.785	3.912	4.039
B	-	0.018	-	-	0.457	-
B_1	-	0.050	-	-	1.270	-
C	-	0.010	-	-	0.254	-
D	1.645	1.650	1.655	41.783	41.91	42.037
E	0.537	0.542	0.547	13.64	13.767	13.894
E_1	0.590	0.600	0.610	14.986	15.240	15.494
E_A	0.630	0.650	0.670	16.002	16.510	17.018
e	-	0.100	-	-	2.540	-
L	0.120	0.130	0.140	3.048	3.302	3.556
θ	0°	-	15°	0°	-	15°

Notes:
1. The maximum value of dimension D includes end flash.
2. Dimension E does not include resin fins.

Package Information

PLCC 32L Outline Dimension

unit: inches/mm



Symbol	Dimensions in inches			Dimensions in mm		
	Min	Nom	Max	Min	Nom	Max
A	-	-	0.134	-	-	3.40
A_1	0.0185	-	-	0.47	-	-
A_2	0.105	0.110	0.115	2.67	2.80	2.93
b_1	0.026	0.028	0.032	0.66	0.71	0.81
b	0.016	0.018	0.021	0.41	0.46	0.54
C	0.008	0.010	0.014	0.20	0.254	0.35
D	0.547	0.550	0.553	13.89	13.97	14.05
E	0.447	0.450	0.453	11.35	11.43	11.51
e	0.044	0.050	0.056	1.12	1.27	1.42
G_D	0.490	0.510	0.530	12.45	12.95	13.46
G_E	0.390	0.410	0.430	9.91	10.41	10.92
H_D	0.585	0.590	0.595	14.86	14.99	15.11
H_E	0.485	0.490	0.495	12.32	12.45	12.57
L	0.075	0.090	0.095	1.91	2.29	2.41
y	-	-	0.003	-	-	0.075
θ	0°	-	10°	0°	-	10°

Notes:
1. Dimensions D and E do not include resin fins.
2. Dimensions G_D & G_E are for PC Board surface mount pad pitch design reference only.